



October 2008

FAIRCHILD
SEMICONDUCTOR®

FDC5661N_F085

N-Channel Logic Level PowerTrench® MOSFET

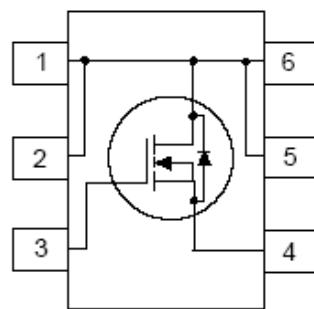
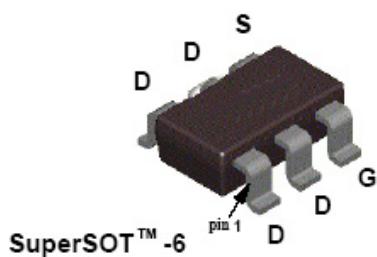
60V, 4A, 60mΩ

Features

- $R_{DS(on)} = 47\text{m}\Omega$ at $V_{GS} = 10\text{V}$, $I_D = 4.3\text{A}$
- $R_{DS(on)} = 60\text{m}\Omega$ at $V_{GS} = 4.5\text{V}$, $I_D = 4\text{A}$
- Typ $Q_{g(TOT)} = 14.5\text{nC}$ at $V_{GS} = 10\text{V}$
- Low Miller Charge
- Qualified to AEC Q101
- RoHS Compliant

Applications

- DC/DC converter
- Motor Drives



MOSFET Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{DSS}	Drain to Source Voltage	60	V
V_{GS}	Gate to Source Voltage	± 20	V
I_D	Drain Current Continuous ($V_{GS} = 10\text{V}$)	4.3	A
	Pulsed	20	
P_D	Power Dissipation	1.6	W
T_J, T_{STG}	Operating and Storage Temperature	-55 to +150	$^\circ\text{C}$

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance Junction to Case	30	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance Junction to Ambient TO-263, 1in ² copper pad area	78	$^\circ\text{C}/\text{W}$

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
.661N	FDC5661N_F085	SSOT-6	7"	8mm	3000 units

Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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Off Characteristics

V_{BDSS}	Drain to Source Breakdown Voltage	$I_D = 250\mu\text{A}, V_{GS} = 0\text{V}$	60	-	-	V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 48\text{V},$	-	-	1	μA
		$V_{GS} = 0\text{V}$	$T_A = 150^\circ\text{C}$	-	250	
I_{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20\text{V}$	-	-	± 100	nA

On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250\mu\text{A}$	1	2.0	3	V
$r_{DS(on)}$	Drain to Source On Resistance	$I_D = 4.3\text{A}, V_{GS} = 10\text{V}$	-	38	47	$\text{m}\Omega$
		$I_D = 4\text{A}, V_{GS} = 4.5\text{V}$	-	46	60	
		$I_D = 4.3\text{A}, V_{GS} = 10\text{V}$	-	69	86	
		$T_J = 150^\circ\text{C}$	-			

Dynamic Characteristics

C_{iss}	Input Capacitance	$V_{DS} = 25\text{V}, V_{GS} = 0\text{V},$ $f = 1\text{MHz}$	-	763	-	pF
C_{oss}	Output Capacitance		-	68	-	pF
C_{rss}	Reverse Transfer Capacitance		-	36	-	pF
R_G	Gate Resistance	$f = 1\text{MHz}$	-	2.6	-	Ω
$Q_{g(TOT)}$	Total Gate Charge at 10V	$V_{GS} = 0 \text{ to } 10\text{V}$	-	14.5	19	nC
Q_{gs}	Gate to Source Gate Charge	$V_{DD} = 30\text{V}$ $I_D = 4.3\text{A}$	-	2.4	-	nC
	Gate to Drain "Miller" Charge		-	2.9	-	nC

Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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Switching Characteristics

t_{on}	Turn-On Time	$V_{DD} = 30\text{V}$, $I_D = 4.3\text{A}$ $V_{GS} = 10\text{V}$, $R_{GS} = 6\Omega$	-	-	17.6	ns
$t_{d(on)}$	Turn-On Delay Time		-	7.2	-	ns
t_r	Rise Time		-	1.6	-	ns
$t_{d(off)}$	Turn-Off Delay Time		-	19.3	-	ns
t_f	Fall Time		-	3.1	-	ns
t_{off}	Turn-Off Time		-	-	36	ns

Drain-Source Diode Characteristics

V_{SD}	Source to Drain Diode Voltage	$I_{SD} = 4.3\text{A}$	-	0.8	1.25	V
		$I_{SD} = 2.1\text{A}$	-	0.8	1.0	
t_{rr}	Reverse Recovery Time	$I_{SD} = 4.3\text{A}$, $dI_{SD}/dt = 100\text{A}/\mu\text{s}$	-	18.4	24	ns
			-	10.0	13	

This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: <http://www.aecouncil.com/>
All Fairchild Semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.

Typical Characteristics

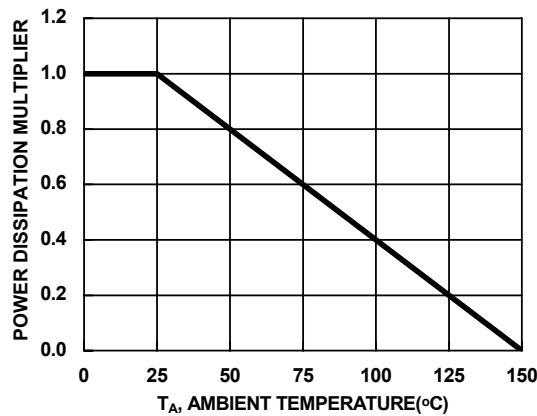


Figure 1. Normalized Power Dissipation vs Ambient Temperature

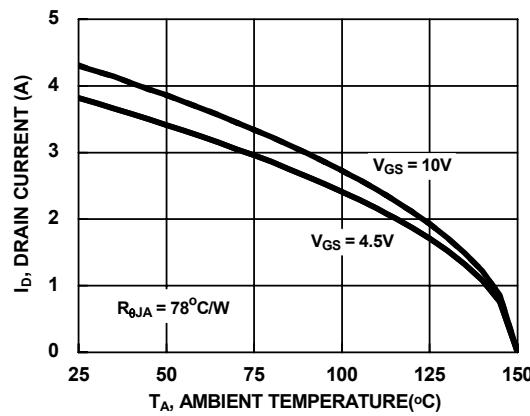


Figure 2. Maximum Continuous Drain Current vs Ambient Temperature

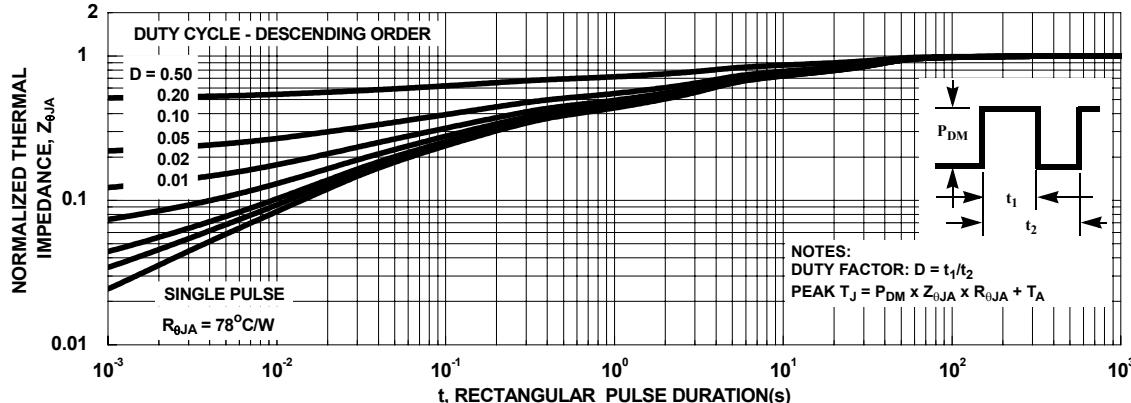


Figure 3. Normalized Maximum Transient Thermal Impedance

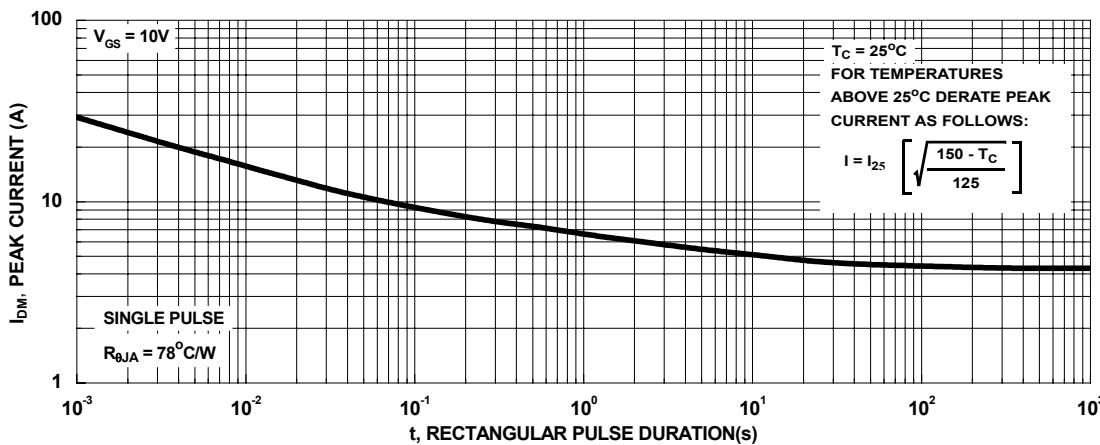


Figure 4. Peak Current Capability

Typical Characteristics

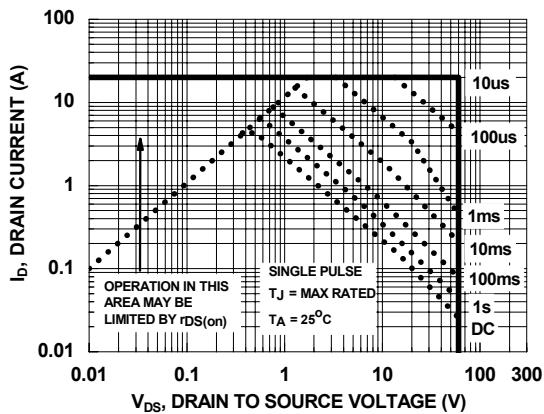


Figure 5. Forward Bias Safe Operating Area

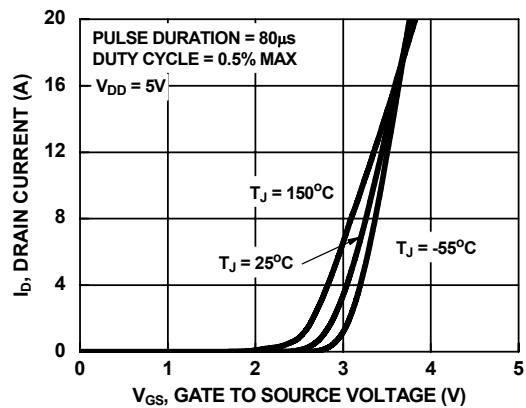


Figure 6. Transfer Characteristics

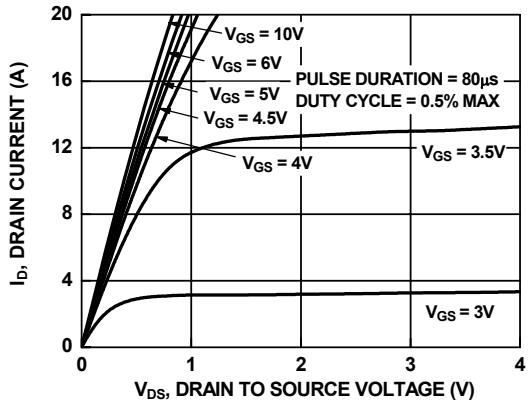


Figure 7. Saturation Characteristics

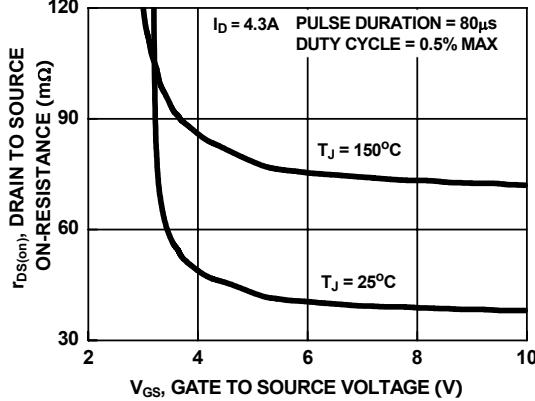


Figure 8. Drain to Source On-Resistance Variation vs Gate to Source Voltage

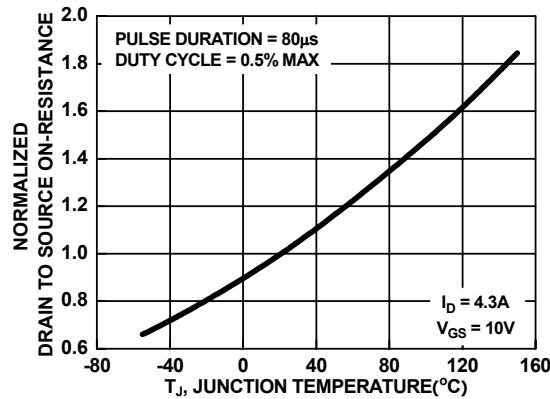


Figure 9. Normalized Drain to Source On-Resistance vs Junction Temperature

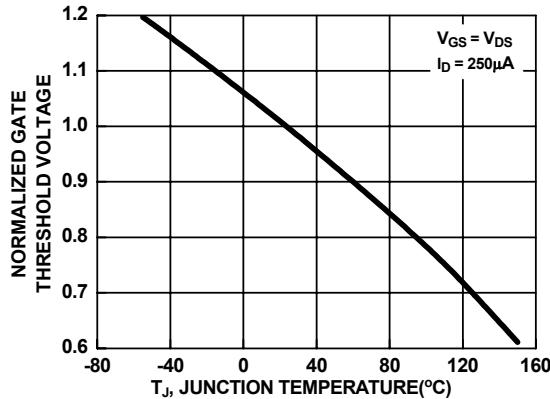


Figure 10. Normalized Gate Threshold Voltage vs Junction Temperature

Typical Characteristics

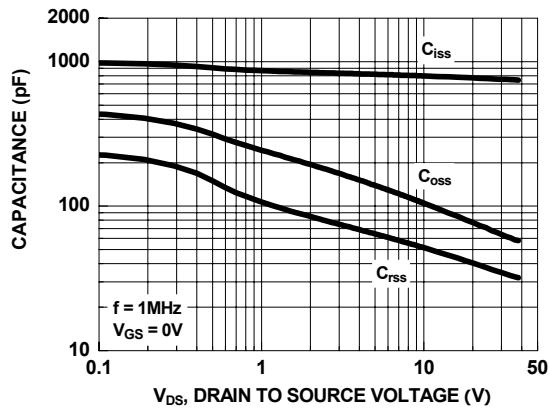
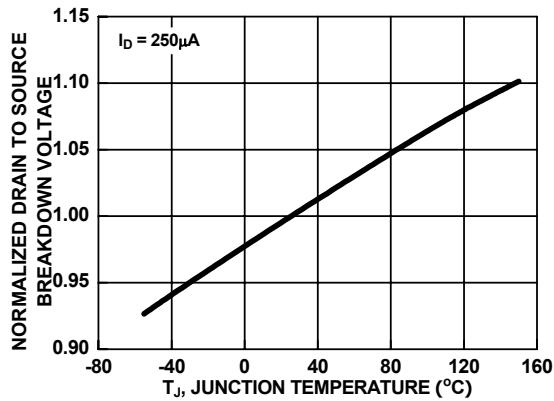
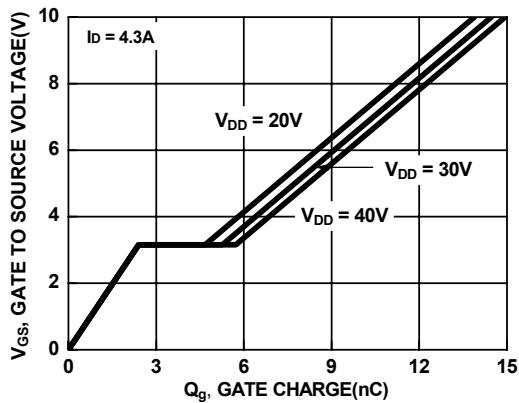


Figure 14.





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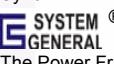
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Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
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